# 4-Bit Transparent Latch/4-to-16 Line Decoder

The MC14514B and MC14515B are two output options of a 4 to 16 line decoder with latched inputs. The MC14514B (output active high option) presents a logical "1" at the selected output, whereas the MC14515B (output active low option) presents a logical "0" at the selected output. The latches are R–S type flip–flops which hold the last input data presented prior to the strobe transition from "1" to "0". These high and low options of a 4–bit latch/4 to 16 line decoder are constructed with N–channel and P–channel enhancement mode devices in a single monolithic structure. The latches are R–S type flip–flops and data is admitted upon a signal incident at the strobe input, decoded, and presented at the output.

These complementary circuits find primary use in decoding applications where low power dissipation and/or high noise immunity is desired.

- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load Over the Rated Temperature Range
- These devices are available in Pb-free package(s). Specifications herein apply to both standard and Pb-free devices. Please see our website at www.onsemi.com for specific Pb-free orderable part numbers, or contact your local ON Semiconductor sales office or representative.

MAXIMUM RATINGS (Voltages Referenced to V<sub>SS</sub>) (Note 1.)

Symbol	Parameter	Value	Unit
V <sub>DD</sub>	DC Supply Voltage Range	-0.5 to +18.0	V
V <sub>in</sub> , V <sub>out</sub>	Input or Output Voltage Range (DC or Transient)	–0.5 to V <sub>DD</sub> + 0.5	V
I <sub>in</sub> , I <sub>out</sub>	Input or Output Current (DC or Transient) per Pin	±10	mA
PD	Power Dissipation, per Package (Note 2.)	500	mW
T <sub>A</sub>	Ambient Temperature Range	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature (8-Second Soldering)	260	°C

1. Maximum Ratings are those values beyond which damage to the device may occur.

2. Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

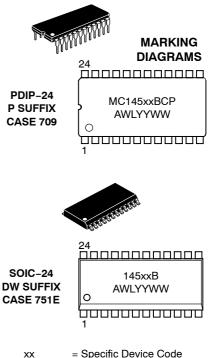
This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}.$ 

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.



# **ON Semiconductor**

http://onsemi.com



XX	:	= Specific Device Cod
Α	:	= Assembly Location
WL	., L :	= Wafer Lot
YY,	Y :	= Year
WV	V, W :	= Work Week

#### **ORDERING INFORMATION**

Device	Package	Shipping
MC14514BCP	PDIP-24	15/Rail
MC14514BDW	SOIC-24	30/Rail
MC14514BDWR2	SOIC-24	1000/Tape & Reel
MC14515BCP	PDIP-24	15/Rail
MC14515BDW	SOIC-24	30/Rail
MC14515BDWR2	SOIC-24	1000/Tape & Reel

#### **PIN ASSIGNMENT**

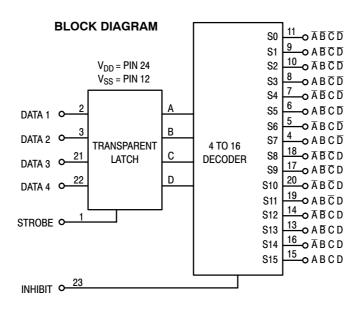
ST [	1•	24	
D1 [	2	23	и пи
D2 [	3	22	D4
S7 [	4	21	] D3
S6 [	5	20	] S10
S5 [	6	19	] S11
S4 [	7	18	] S8
S3 [	8	17	] S9
S1 [	9	16	] S14
S2 [	10	15	] S15
S0 [	11	14	] S12
V <sub>SS</sub> [	12	13	] S13

#### DECODE TRUTH TABLE (Strobe = 1)\*

		Data Inj	outs		Selected Output
Inhibit	D	с	в	Α	MC14514 = Logic "1" MC14515 = Logic "0"
0	0	0	0	0	S0
0	0	0	0	1	S1
0	0	0	1	0	S2
0	0	0	1	1	S3
0	0	1	0	0	S4
0	0	1	0	1	S5
0	0	1	1	0	S6
0	0	1	1	1	S7
0	1	0	0	0	S8
0	1	0	0	1	S9
0	1	0	1	0	S10
0	1	0	1	1	S11
0	1	1	0	0	S12
0	1	1	0	1	S13
0	1	1	1	0	S14
0	1	1	1	1	S15
1	х	х	х	Х	All Outputs = 0, MC14514 All Outputs = 1, MC14515

X = Don't Care

\*Strobe = 0, Data is latched



ELECTRICAL CHARACTERISTICS	(Voltages Referenced to V <sub>SS</sub> )
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			V <sub>DD</sub>	- 5	5°C		25°C		125	5°C	
Characteristic		Symbol	Vdc Min		Max	Min	Тур <sup>(3.)</sup>	Max	Min	Max	Unit
Output Voltage V <sub>in</sub> = V <sub>DD</sub> or 0	"0" Level	V <sub>OL</sub>	5.0 10 15	 	0.05 0.05 0.05	 	0 0 0	0.05 0.05 0.05	 	0.05 0.05 0.05	Vdc
$V_{in} = 0 \text{ or } V_{DD}$	"1" Level	V <sub>OH</sub>	5.0 10 15	4.95 9.95 14.95		4.95 9.95 14.95	5.0 10 15		4.95 9.95 14.95		Vdc
Input Voltage $(V_O = 4.5 \text{ or } 0.5 \text{ Vdc})$ $(V_O = 9.0 \text{ or } 1.0 \text{ Vdc})$ $(V_O = 13.5 \text{ or } 1.5 \text{ Vdc})$	"0" Level	V <sub>IL</sub>	5.0 10 15		1.5 3.0 4.0	 	2.25 4.50 6.75	1.5 3.0 4.0		1.5 3.0 4.0	Vdc
$\begin{array}{l} (V_{O} = 0.5 \text{ or } 4.5 \text{ Vdc}) \\ (V_{O} = 1.0 \text{ or } 9.0 \text{ Vdc}) \\ (V_{O} = 1.5 \text{ or } 13.5 \text{ Vdc}) \end{array}$	"1" Level	V <sub>IH</sub>	5.0 10 15	3.5 7.0 11		3.5 7.0 11	2.75 5.50 8.25		3.5 7.0 11		Vdc
$\begin{array}{l} \text{Output Drive Current} \\ (V_{OH} = 2.5 \ \text{Vdc}) \\ (V_{OH} = 4.6 \ \text{Vdc}) \\ (V_{OH} = 9.5 \ \text{Vdc}) \\ (V_{OH} = 13.5 \ \text{Vdc}) \end{array}$	Source	I <sub>OH</sub>	5.0 5.0 10 15	- 1.2 - 0.25 - 0.62 - 1.8		- 1.0 - 0.2 - 0.5 - 1.5	- 1.7 - 0.36 - 0.9 - 3.5		- 0.7 - 0.14 - 0.35 - 1.1	 	mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	Sink	I <sub>OL</sub>	5.0 10 15	0.64 1.6 4.2		0.51 1.3 3.4	0.88 2.25 8.8		0.36 0.9 2.4		mAdc
Input Current		l <sub>in</sub>	15	_	± 0.1	_	±0.00001	± 0.1	_	± 1.0	μAdc
Input Capacitance (V <sub>in</sub> = 0)		C <sub>in</sub>	_	—	_	—	5.0	7.5	—	_	pF
Quiescent Current (Per Package)		I <sub>DD</sub>	5.0 10 15		5.0 10 20		0.005 0.010 0.015	5.0 10 20		150 300 600	μAdc
Total Supply Current <sup>(4.)</sup> <sup>(5.)</sup> (Dynamic plus Quiescent, Per Package) (C <sub>L</sub> = 50 pF on all outputs, all buffers switching)		Ι <sub>ΤL</sub>	5.0 10 15			I <sub>T</sub> = (2	.35 μA/kHz) .70 μA/kHz) .05 μA/kHz)	f + I <sub>DD</sub>			μAdc

Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
 The formulas given are for the typical characteristics only at 25°C.

5. To calculate total supply current at loads other than 50 pF:

 $I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$ 

where: I<sub>T</sub> is in  $\mu$ A (per package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> - V<sub>SS</sub>) in volts, f in kHz is input frequency, and k = 0.002.

## SWITCHING CHARACTERISTICS <sup>(6.)</sup> ( $C_L$ = 50 pF, $T_A$ = 25°C)

				All Types		
Characteristic	Symbol	V <sub>DD</sub>	Min	Тур <sup>(7.)</sup>	Max	Unit
Output Rise Time $t_{TLH} = (3.0 \text{ ns/pF}) C_L + 30 \text{ ns}$ $t_{TLH} = (1.5 \text{ ns/pF}) C_L + 15 \text{ ns}$ $t_{TLH} = (1.1 \text{ ns/pF}) C_L + 10 \text{ ns}$	ttlh	5.0 10 15		180 90 65	360 180 130	ns
Output Fall Time $t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ $t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ $t_{THL} = (0.55 \text{ ns/pF}) C_L + 9.5 \text{ ns}$	t <sub>THL</sub>	5.0 10 15		100 50 40	200 100 80	ns
Propagation Delay Time; Data, Strobe to S $t_{PLH}$ , $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 465 \text{ ns}$ $t_{PLH}$ , $t_{PHL} = (0.86 \text{ ns/pF}) C_L + 192 \text{ ns}$ $t_{PLH}$ , $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 125 \text{ ns}$	t <sub>PLH</sub> , t <sub>PHL</sub>	5.0 10 15		550 225 150	1100 450 300	ns
Inhibit Propagation Delay Times $t_{PLH}$ , $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 315 \text{ ns}$ $t_{PLH}$ , $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 117 \text{ ns}$ $t_{PLH}$ , $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 75 \text{ ns}$	t <sub>PLH</sub> , t <sub>PHL</sub>	5.0 10 15		400 150 100	800 300 200	ns
Setup Time Data to Strobe	t <sub>su</sub>	5.0 10 15	250 100 75	125 50 38		ns
Hold Time Strobe to Data	t <sub>h</sub>	5.0 10 15	- 20 0 10	- 100 - 40 - 30		ns
Strobe Pulse Width	twн	5.0 10 15	350 100 75	175 50 38		ns

6. The formulas given are for the typical characteristics only at  $25^{\circ}$ C.

7. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

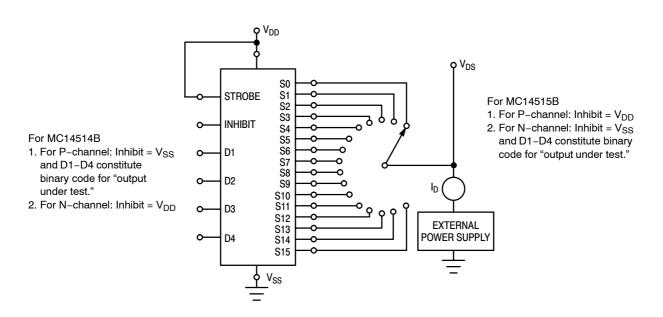
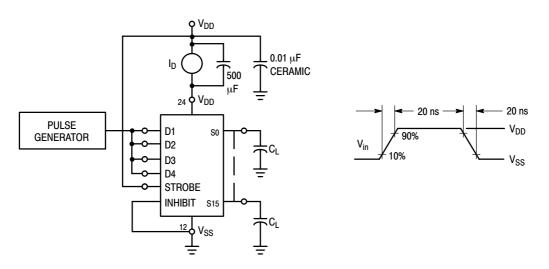


Figure 1. Drain Characteristics Test Circuit





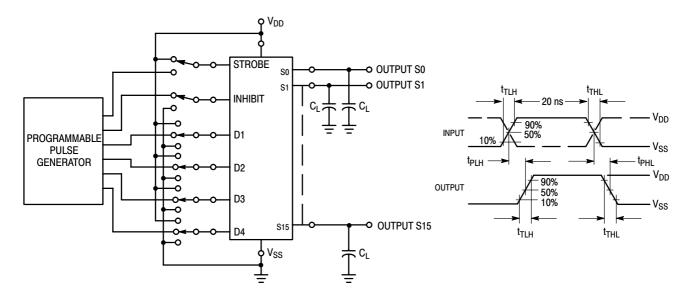
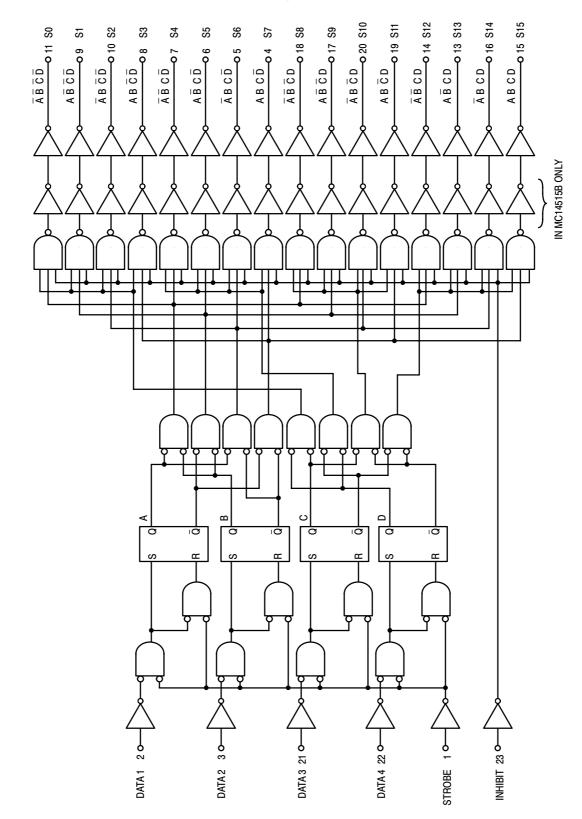


Figure 3. Switching Time Test Circuit and Waveforms



LOGIC DIAGRAM

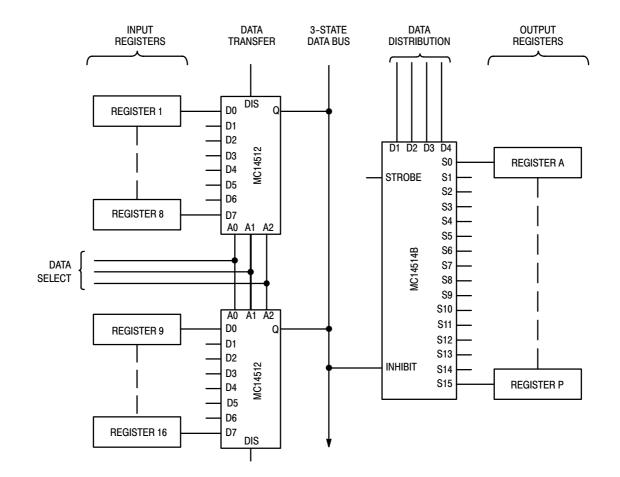
#### COMPLEX DATA ROUTING

Two MC14512 eight-channel data selectors are used here with the MC14514B four-bit latch/decoder to effect a complex data routing system. A total of 16 inputs from data registers are selected and transferred via a 3-state data bus to a data distributor for rearrangement and entry into 16 output registers. In this way sequential data can be re-routed or intermixed according to patterns determined by data select and distribution inputs.

Data is placed into the routing scheme via the eight inputs on both MC14512 data selectors. One register is assigned to each input. The signals on A0, A1, and A2 choose one of eight inputs for transfer out to the 3-state data bus. A fourth signal, labelled Dis, disables one of the MC14512 selectors, assuring transfer of data from only one register.

In addition to a choice of input registers, 1 thru 16, the rate of transfer of the sequential information can also be varied. That is, if the MC14512 were addressed at a rate that is eight times faster then the shift frequency of the input registers, the most significant bit (MSB) from each register could be selected for transfer to the data bus. Therefore, all of the most significant bits from all of the registers can be transferred to the data bus before the next most significant bit is presented for transfer by the input registers.

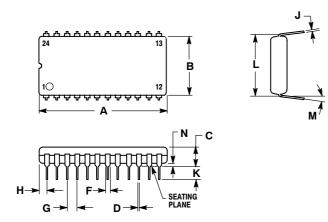
Information from the 3-state bus is redistributed by the MC14514B four-bit latch/decoder. Using the four-bit address, D1 thru D4, the information on the inhibit line can be transferred to the addressed output line to the desired output registers, A thru P. This distribution of data bits to the output registers can be made in many complex patterns. For example, all of the most significant bits from the input registers can be routed into output register A, all of the next most significant bits into register B, etc. In this way horizontal, vertical, or other methods of data slicing can be implemented.



#### DATA ROUTING SYSTEM

### PACKAGE DIMENSIONS

PDIP-24 **P SUFFIX** PLASTIC DIP PACKAGE CASE 709-02 ISSUE C



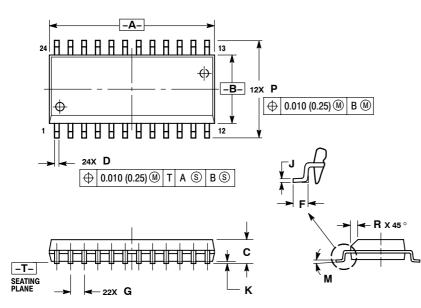
NOTES:

IOTES: 1. POSITIONAL TOLERANCE OF LEADS (D), SHALL BE WITHIN 0.25 (0.010) AT MAXIMUM MATERIAL CONDITION, IN RELATION TO SEATING PLANE AND EACH OTHER. 2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. 3. DIMENSION B DOES NOT INCLUDE MOLD FLASH. 4. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIM	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	1.235	1.265	31.37	32.13	
В	0.540	0.560	13.72	14.22	
С	0.155	0.200	3.94	5.08	
D	0.014	0.022	0.36	0.56	
F	0.040	0.060	1.02	1.52	
G	0.100	BSC	2.54 BSC		
Н	0.065	0.080	1.65	2.03	
J	0.008	0.015	0.20	0.38	
Κ	0.115	0.135	2.92	3.43	
L	0.600	BSC	15.24	BSC	
М	0 °	15°	0 °	15°	
Ν	0.020	0.040	0.51	1.02	

### PACKAGE DIMENSIONS

SOIC-24 **DW SUFFIX** PLASTIC SOIC PACKAGE CASE 751E-04 ISSUE E



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  JIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	15.25	15.54	0.601	0.612	
В	7.40	7.60	0.292	0.299	
С	2.35	2.65	0.093	0.104	
D	0.35	0.49	0.014	0.019	
F	0.41	0.90	0.016	0.035	
G	1.27	BSC	0.050 BSC		
J	0.23	0.32	0.009	0.013	
K	0.13	0.29	0.005	0.011	
М	0 °	8°	0 °	8°	
Ρ	10.05	10.55	0.395	0.415	
R	0.25	0.75	0.010	0.029	

# <u>Notes</u>

# <u>Notes</u>

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